## **JEOL JEM-ARM200F NEOARM TECHNICAL DETAILS**

ACCELERATION VOLTAGE	From 30 to 200 kV				
ACCELERATION VOLTAGE STABILITY	5 x 10 <sup>-7</sup> /min				
ELECTRO-OPTICAL ALIGNMENTS	Automatic for three different acceleration voltages: 60, 80 and 200 kV				
PUMP SYSTEM	<ul> <li>Oil-free, with vacuum values:</li> <li>1 x 10<sup>-8</sup> Pa at the end of the accelerating tube, or about 10-10 Pa in the cathode area</li> <li>2 x 10<sup>-5</sup> Pa at column and sample chamber level</li> </ul>				
ELECTRON SOURCE	<ul> <li>Cold cathode field emission with high spatial and temporal coherence (Cold-FEG) with Flash &amp; Gottechnology:         <ul> <li>Energy spread ≤ 0.33eV to 200kV (FWHM)</li> <li>Brilliance 1.5 · 10<sup>-9</sup> A/cm<sup>2</sup> · sr at 200kV</li> <li>Current density: ranges from 0 - 10 nA</li> <li>Temporal coherence: longitudinal of 1.17·10<sup>-14</sup> m and transverse of 2.04·10<sup>-16</sup> m</li> <li>Source: at a transverse coherence length of about 42.4 nm and a longitudinal coherence length of approximately 2.43 μm at 200kV</li> </ul> </li> </ul>				
CORRECTORS	<ul> <li>ASCOR-type STEM corrector that can correct up to the 5<sup>th</sup> order of aberration</li> <li>CETCOR-type TEM corrector that can correct up to the 4<sup>th</sup> order of aberration</li> </ul>				
EMISSION CURRENT	From 0 to 15 uA				
CURRENT AT SAMPLE LEVEL	From 0 e 10 nA				
OBJECTIVE LENS FEATURES	<ul> <li>The NEOARM is equipped with HR "High Resolution" type polar expansions</li> <li>The distance between the polar expansions of the objective lens is &gt; 4 mm</li> <li>In situ experiments, 3D high-angle tilt tomography, cryo, etc.</li> </ul>				
PHASE CONTRAST RESOLUTION	At 200 kV: 72 pm				

STEM-HAADF MODE RESOLUTION	At 200 kV: 73 pm on GaN, obtained in single frame acquisition mode, 63pm on GaN which is available in frame accumulation acquisition mode			
DIAPHRAGMS	<ul> <li>Condenser lens: 10, 20, 30, 40, 50, 70, 100, 150 μm</li> <li>Objective lens (diffraction plane): 5, 30, 40, 60 μm</li> <li>Selected area (image plane): 10, 20, 50, 100 μm</li> </ul>			
INFORMATION LIMIT	90 pm			
MINIMUM DIAMETER OF THE PROBE	Up to 63 pm with a current density of 30 pA			
TEMPORAL COHERENCE	Longitudinal of 1.17·10 <sup>-14</sup> m and transverse of 2.04·10 <sup>-16</sup> m			
SPATIAL COHERENCE	Transverse coherence approximately 42.4 nm and a longitudinal coherence length of about 2.43 μm at 200 kV			
GONIOMETRIC EXCURSION	Controlled with a trackball or graphical interface:  • X= ± 1 mm  • Y= ± 1 mm  • Z= ± 0,2 mm			
SYSTEM STABILITY	<ul> <li>Atomic Resolution Microscope (ARM) platform:</li> <li>Column with increased diameter and new base frame with anti-vibration system and optimized gravity center, to achieve the atomic resolution</li> <li>Protective cover for sample holder</li> <li>Arrangement and reduced weight of pumps on column</li> <li>Sample drift compensation system in STEM-EDS mode, operating in the range of drift ± 100 nm</li> </ul>			
SAMPLE HOLDER AXIAL TILT	<ul> <li>For combined EDS and crystallographic analysis:</li> <li>X= ± 30°, Y= ± 30°</li> <li>For 3D tomography, maximum tilt angle of ± 80°</li> <li>Cryogenic double tilt specimen holder with maximum tilt in X, Y of ± 15°</li> </ul>			

DETECTOR	<ul> <li>Dual EDS detector, with SDD technology:</li> <li>Active area of each detector 100 mm²:</li> <li>133 eV Resolution</li> <li>Spurious spikes: ≤1%</li> <li>P/B ratio on Ni: ≥4000</li> <li>Overall solid angle: a solid angle of 1.76 sr is achieved by the two detectors to ensure maximum analytical performance</li> <li>Minimum dwell time in fast mapping conditions is 10 μs</li> </ul>				
EDS CONTROL SOFTWARE	<ul> <li>Point analysis, line scan, mapping X</li> <li>Qualitative and quantitative analysis including by Cliff-Lorimer method</li> <li>Self-identification of peaks</li> </ul>				
EXPORT OF EDS INFORMATION	Smile View Map, Microsoft Word, Power Point etc.				
NEOARM EQUIPMENT	<ul> <li>Gatan Imaging Filter (GIF) type "Continuum ER," includes:         <ul> <li>New CMOS detector with low background noise and high dynamic range, 2048 · 2048 pixels with Gatan's revolutionary patented fast-decay XCR scintillator with 18 μm pixel size</li> <li>Ultrafast electrostatic shutter (100ns)</li> <li>High-speed DualEELS™ with 2 kV offset</li> <li>Specific BF/DF detector with integrated beam stopper dedicated for STEM-EELS applications</li> <li>Aperture mask with 81 holes, 9 mm diameter imaging aperture, 5.0 / 2.5 mm diameter EELS apertures and energy selection unit</li> </ul> </li> <li>On-line and off-line licensing of Gatan Digital Micrograph</li> </ul>				
DIGITAL CAMERA	CMOS Gatan Rio16, with the following features:  • 16 MP (4,096 · 4,096)  • Active sensor area 36.9 · 36.9 mm²  • Pixels size: 9 um  • Read out speed maximal 20 fps  • Displayed and saved image: sum with sample drift correction of 20 fps  • Dynamic range with frame sum: ≥16 bits  • Installation position: placed on axis to the electron beam, retractable and GIF compatible  • Primary acceleration voltage: 30-200 kV				

CAMERA	<ul> <li>GATAN "K3 IS base" with the following features:</li> <li>14.2 MP (3,456 · 4,092)</li> <li>Pixel size: 5 μm</li> <li>Working mode: standard, in-situ and counting modes</li> <li>Read out: full resolution 1500 fps with on line frame accumulation system that allows recording of images derived from the sum of at least 20 fps (standard mode). In the in-situ mode, 150 fps recording is possible at full resolution and up to 3,500 fps (256 x 256 pixels)</li> <li>Accelerating voltage: 80-200 kV</li> </ul>		
VACUUM SYSTEM	<ul> <li>Fully automatic with integrated diagnostics in the TEM GUI, oil-free, and consisting of:</li> <li>NEG pump (200L/s)</li> <li>Ion pumps at the source (200L/s and 20L/s), ion pump (150L/s)</li> <li>Turbomolecular pump (300L/s) in the column and dual scroll pumps (each 500L/s) for pre-vacuum</li> </ul>		
STEM DETECTOR	<ul> <li>Configuration:</li> <li>Bright Field (BF): of P47 phosphor scintillator type with 8mm diameter, 1us/dwell time and with sensitivity expressed as ~100% quantum efficiency</li> <li>Annular Bright Field (ADF): phosphor-type P47 annular with 0.8 mm inner diameter and 1.6 mm outer diameter, 1us/dwell time and with sensitivity expressed as ~100% quantum efficiency</li> <li>Dark field (DF): high-sensitivity YAP-Ce/P47 hybrid detector having inner diameter of 4mm and outer diameter of 16mm, 1us/dwell time and with sensitivity expressed as ~100% quantum efficiency.</li> <li>New High Angle Annular Dark field (DF) "Perfect Sight": high-sensitivity hybrid detector</li> <li>YAP-Ce/P47, having inner diameter of 4mm and outer diameter of 16mm, 1us/dwell time and with sensitivity expressed as ~100% quantum efficiency</li> <li>Maximum resolution in pixels for individual acquisition STEM channel: 4096</li> <li>Detector collection angle as a function of camera length</li> </ul>		
TEM MAGNIFICATIONS	From 50 up to 2,000,000		
STEM MAGNIFICATIONS	From 200 up to 150,000,000		